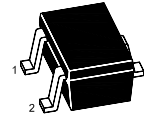
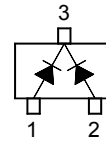


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Silicon Epitaxial Planar Switching Diode

Applications

- Ultra high speed switching



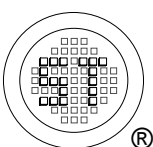
SOT-323 Plastic Package
Marking Code: PH

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Maximum (Peak) Reverse Voltage	V_{RM}	85	V
Reverse Voltage	V_R	80	V
Average Rectified Forward Current	$I_{F(AV)}$	100	mA
Maximum (Peak) Forward Current	I_{FM}	300	mA
Non-repetitive Peak Forward Surge Current ($t_p = 10$ ms)	I_{FSM}	2	A
Total Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 100$ mA	V_F	-	1.2	V
Reverse Current at $V_R = 30$ V at $V_R = 80$ V	I_R	-	0.1 0.5	μA
Total Capacitance at $V_R = 0$, $f = 1$ MHz	C_T	-	3	pF
Reverse Recovery Time at $I_F = 10$ mA, $V_R = 6$ V, $I_{rr} = 1$ mA, $R_L = 100 \Omega$	t_{rr}	-	4	ns

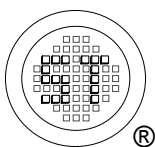
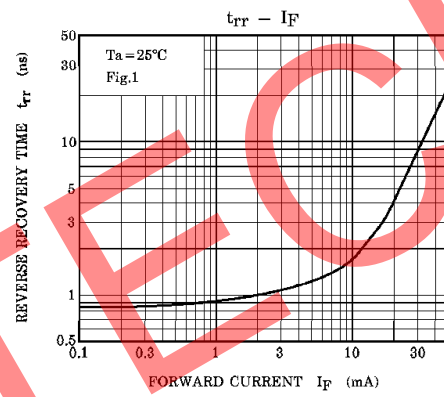
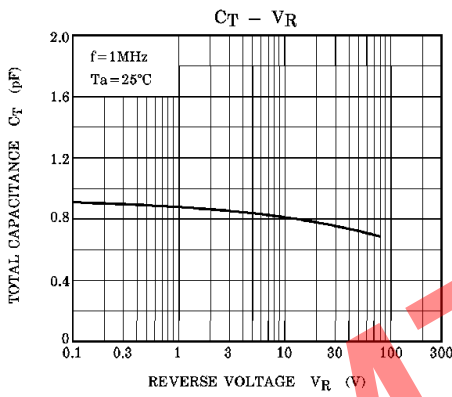
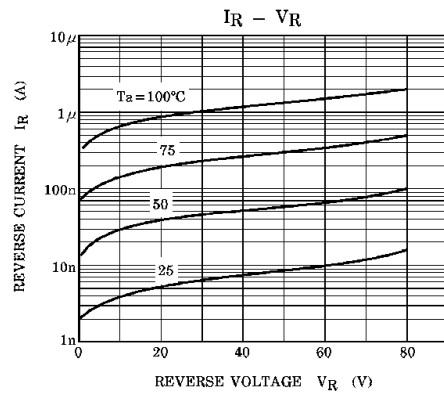
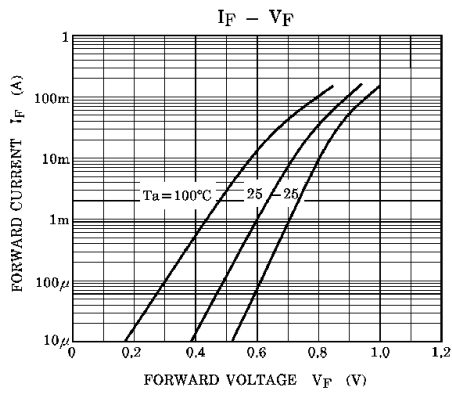


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